

ON Semiconductor®

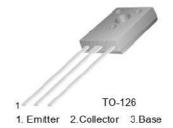
# BD135 / 137 / 139 NPN Epitaxial Silicon Transistor

#### **Features**

- Complement to BD136, BD138 and BD140 respectively

### **Applications**

· Medium Power Linear and Switching



### **Ordering Information**

Part Number	Marking	Package	Packing Method	
BD13516S	BD135-16		Bulk	
BD1356STU	BD135-6	TO-126 3L		
BD13510STU	BD135-10			
BD13516STU	BD135-16		Rail	
BD13716STU	BD137-16			
BD13710STU	BD137-10			
BD13716S	BD137-16		Bulk	
BD13916STU	BD139-16		Rail	
BD13910S	BD139-10		Date	
BD13916S	BD139-16		Bulk	
BD1396STU	BD139-6		Rail	
BD13910STU	BD139-10		Kali	

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter		Value	Units
		BD135	45	
V <sub>CBO</sub> Collector-Base Voltage	Collector-Base Voltage	BD137	60	V
		BD139	80	
V <sub>CEO</sub> Collector-Emitter Voltage		BD135	45	
	Collector-Emitter Voltage	BD137	60	_ v
		BD139	80	
V <sub>EBO</sub>	Emitter-Base Voltage		5	V
I <sub>C</sub>	Collector Current (DC)		1.5	A
I <sub>CP</sub>	Collector Current (Pulse)		3.0	A
IB	Base Current		0.5	A
Pc	Device Dissingtion	T <sub>C</sub> = 25°C	12.5	W
	Device Dissipation	T <sub>A</sub> = 25°C	1.25	W
TJ	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		- 55 to +150	°C

#### **Electrical Characteristics**

Values are at  $T_C$  = 25°C unless otherwise noted.

Symbol	Parameter		Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage	BD135	I <sub>C</sub> = 30 mA, I <sub>B</sub> = 0	45			V
		BD137		60			
		BD139		80			
I <sub>CBO</sub>	Collector Cut-off Current		V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0			0.1	μА
I <sub>EBO</sub>	Emitter Cut-off Current		V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0			10	μА
h <sub>FE1</sub>			$V_{CE} = 2 \text{ V, } I_{C} = 5 \text{ mA}$	25			
h <sub>FE2</sub>	DC Current Gain		V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A	25			
h <sub>FE3</sub>			V <sub>CE</sub> = 2 V, I <sub>C</sub> = 150 mA	40		250	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage		$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$			0.5	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage		V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A			1	V

### **h**FE Classification

Classification	6	10	16
h <sub>FE3</sub>	40 ~ 100	63 ~ 160	100 ~ 250

### **Typical Performance Characteristics**

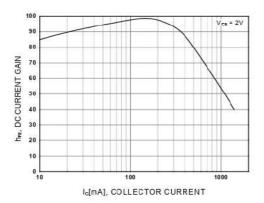


Figure 1. DC current Gain

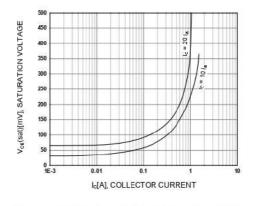


Figure 2. Collector-Emitter Saturation Voltage

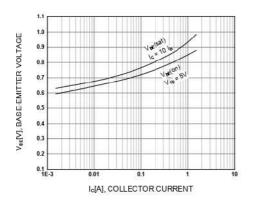


Figure 3. Base-Emitter Voltage

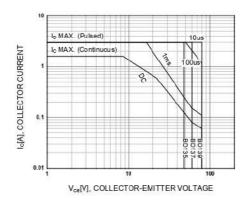


Figure 4. Safe Operating Area

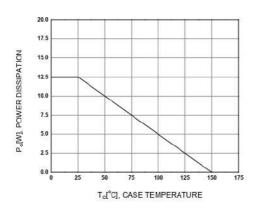
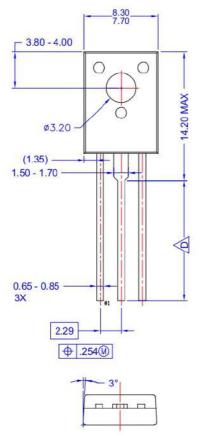
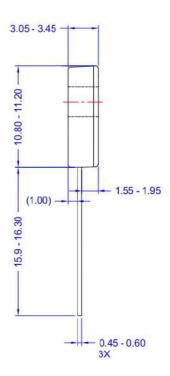


Figure 5. Power Derating

### **Physical Dimensions**

## TO-126 3L





PRODUCTION CODE	TERMINAL LENGTH "D"
TSSTU	3.45-4.05
TSTU	2.36-2.96
NONE (STD LENGTH)	12.76-13.36

#### NOTES:

- A) THIS PACKAGE DOES NOT COMPLY TO ANY CURENT PACKAGING STANDARD.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH,
- AND TIE BAR EXTRUSIONS.
- D FOR TERMINAL LENGTH SEE TABLE
- E) DRAWING FILE NAME AND REVISION: MKT-TO126AArev1

Figure 6. TO-126 (SOT-32) UNIFIED DRAWING (TSTU, TSSTU, STANDARD)

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